

SI4900DY-T1-E3 Information


For Reference Only

Part Number [SI4900DY-T1-E3](#)
Manufacturer Vishay Siliconix
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Arrays](#)
Description MOSFET 2N-CH 60V 5.3A 8-SOIC
Package 8-SOIC (0.154", 3.90mm Width)
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


SI4900DY-T1-E3 Specifications

Manufacturer Part Number	SI4900DY-T1-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	TrenchFET?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	5.3A
Rds On (Max) @ Id, Vgs	58 mOhm @ 4.3A, 10V
Vgs(th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	665pF @ 15V
Power - Max	3.1W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SO

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SI4900DY-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI4900DY-T1-E3 Payment Methods



SI4900DY-T1-E3 Shipping Methods



If you have any question about SI4900DY-T1-E3, please do not hesitate to contact us!

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